

Eliminating Anomalous Low Energy Tails in Hard X-ray TES Micro-calorimeters Using Electroplated Bismuth

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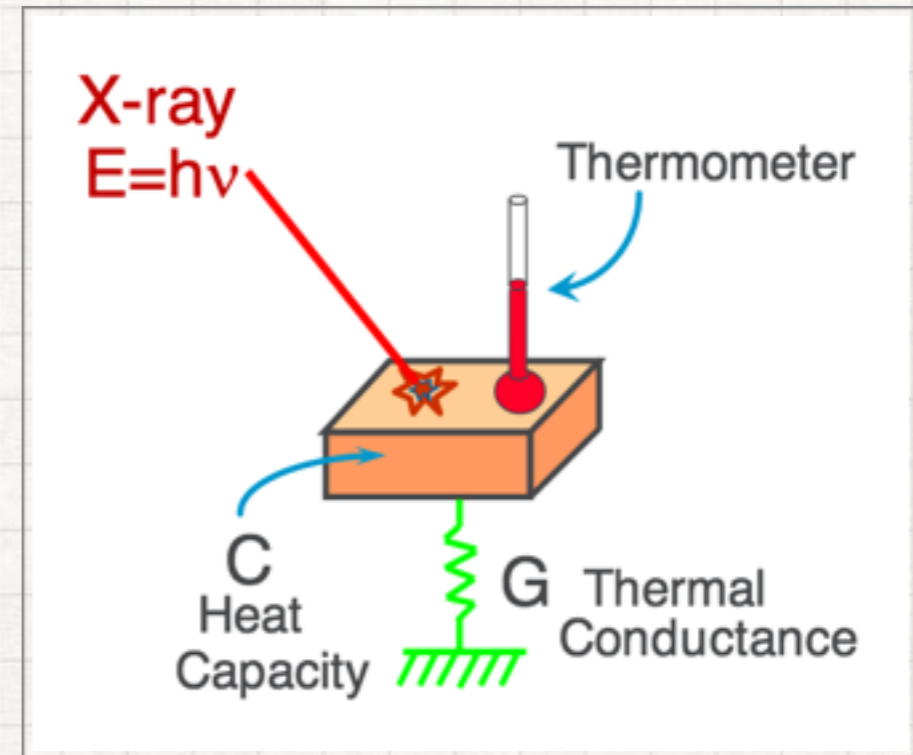
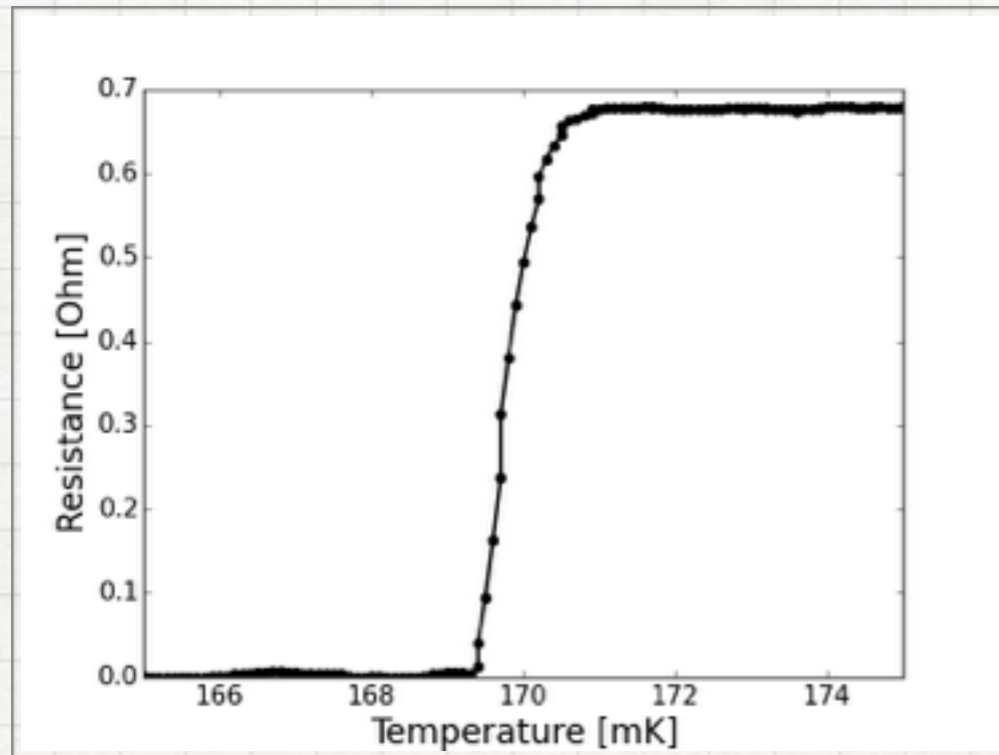
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TES (Transition Edge Sensor) can be used as **calorimeter** to measure x-ray photon energy.



Absorber:

sufficient x-ray stopping power

small specific heat capacity ($\Delta E \propto \sqrt{C}$)

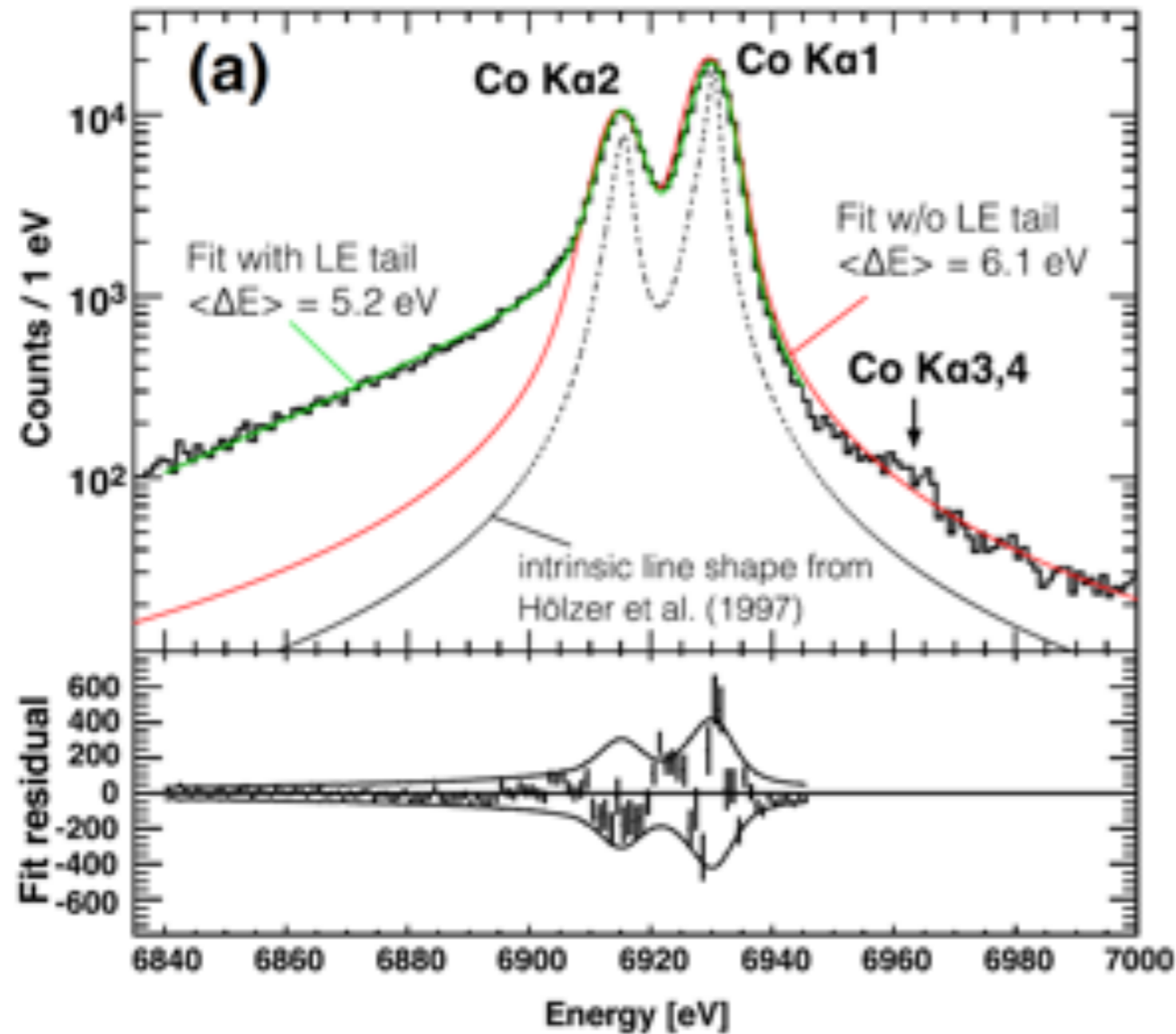
Bi

semimetal: small C

atomic number 83: large x-ray stopping power

problem: evaporated Bi produces low energy tail

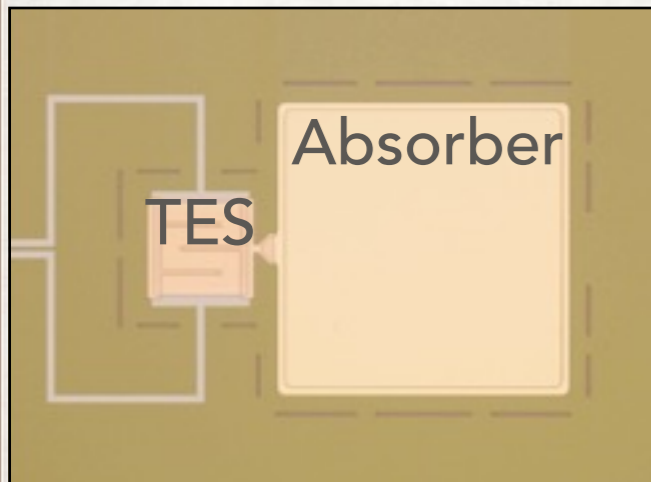
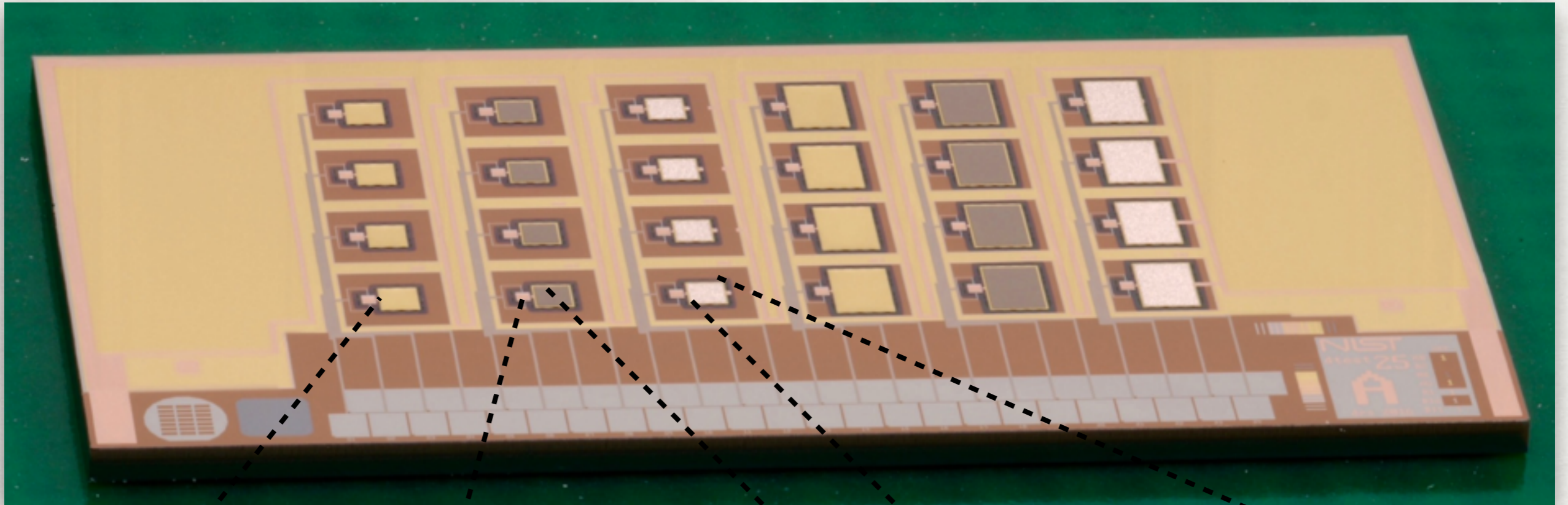
low energy tail produced by evaporated Bi



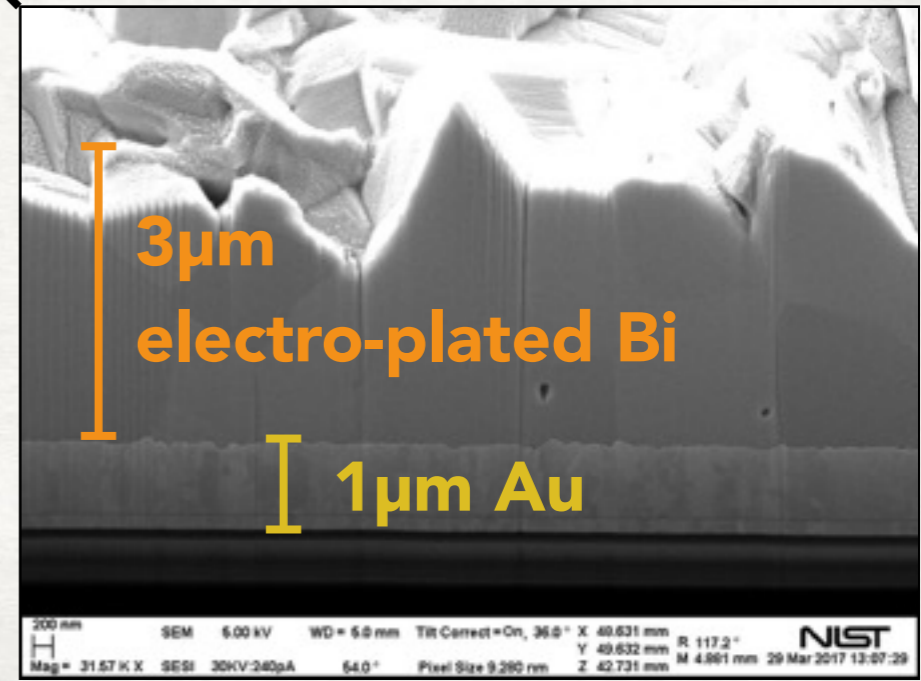
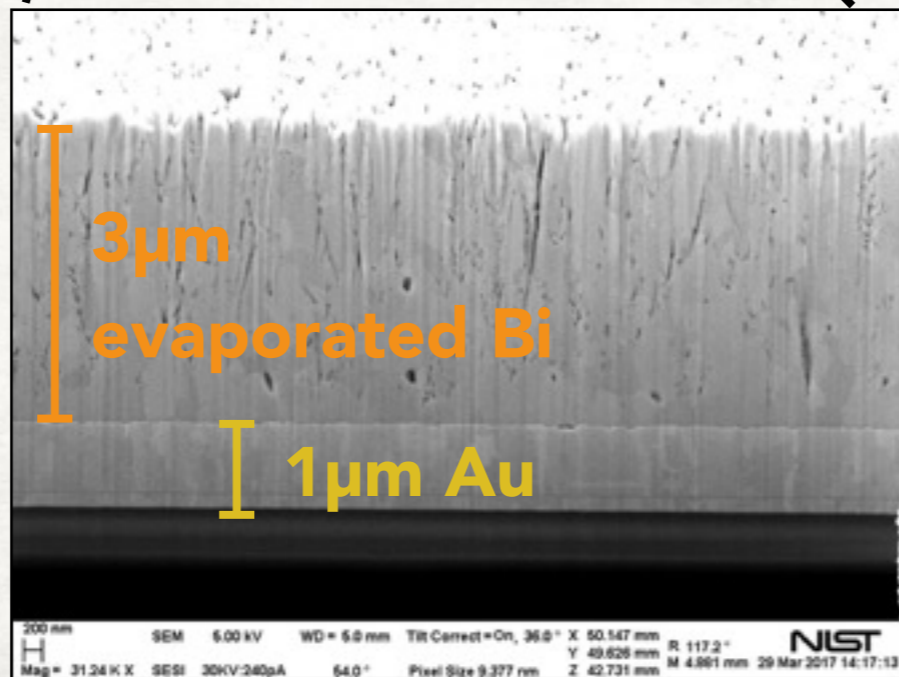
Other deposition method?
electro-plating Bi

Tatsuno, H., Doriese, W.B., Bennett, D.A. et al. *J Low Temp Phys* (2016) 184: 930. doi:[10.1007/s10909-016-1491-2](https://doi.org/10.1007/s10909-016-1491-2)

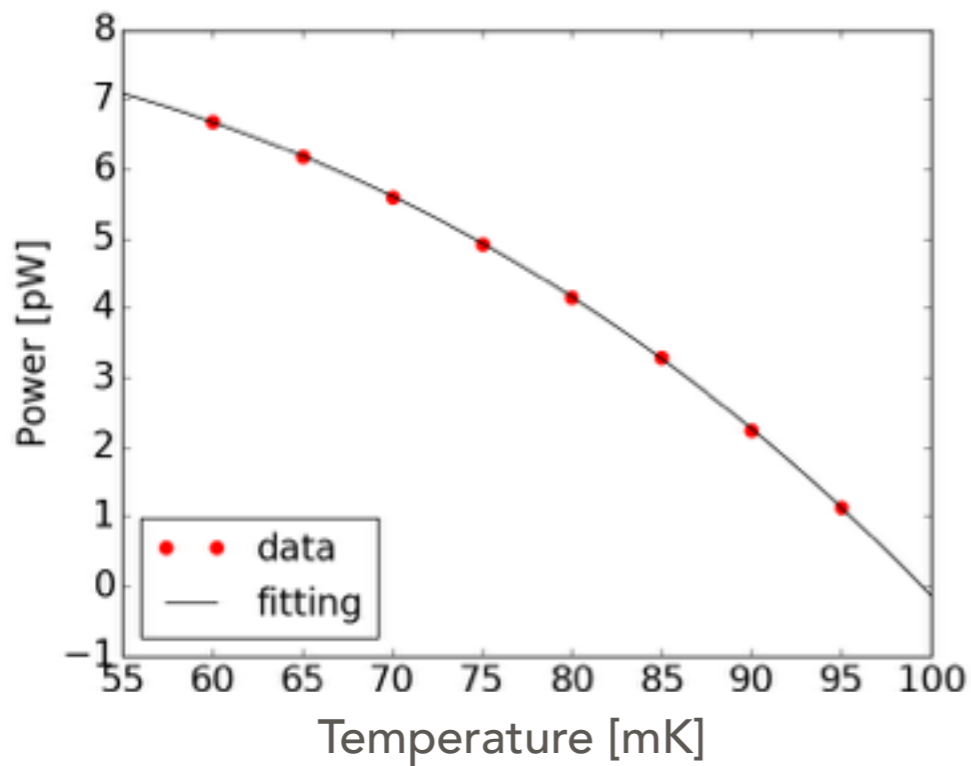
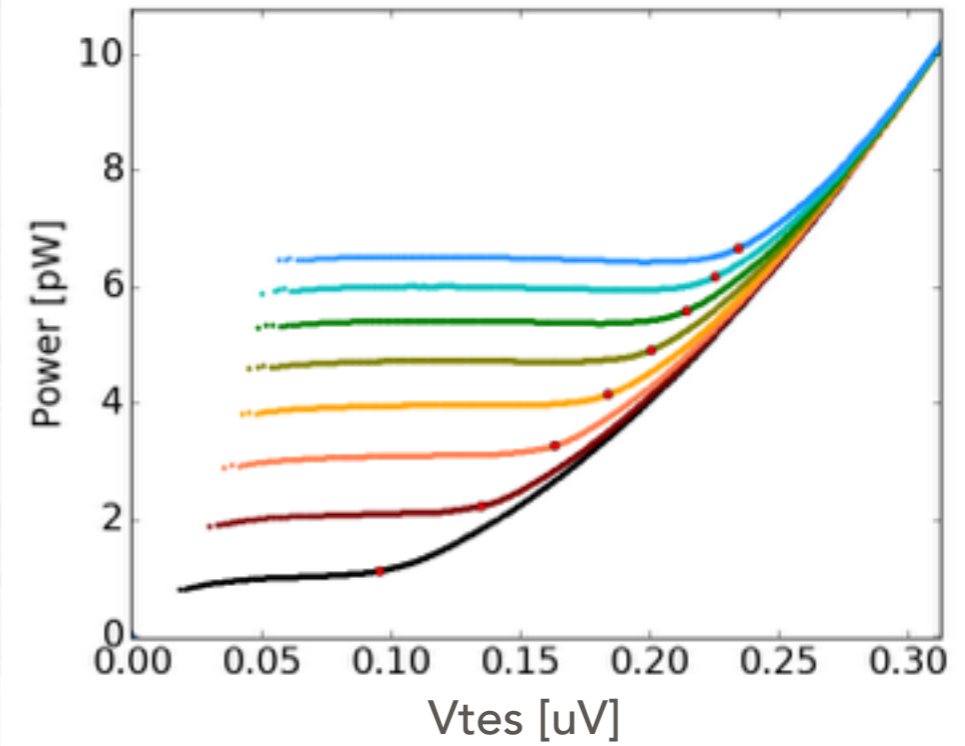
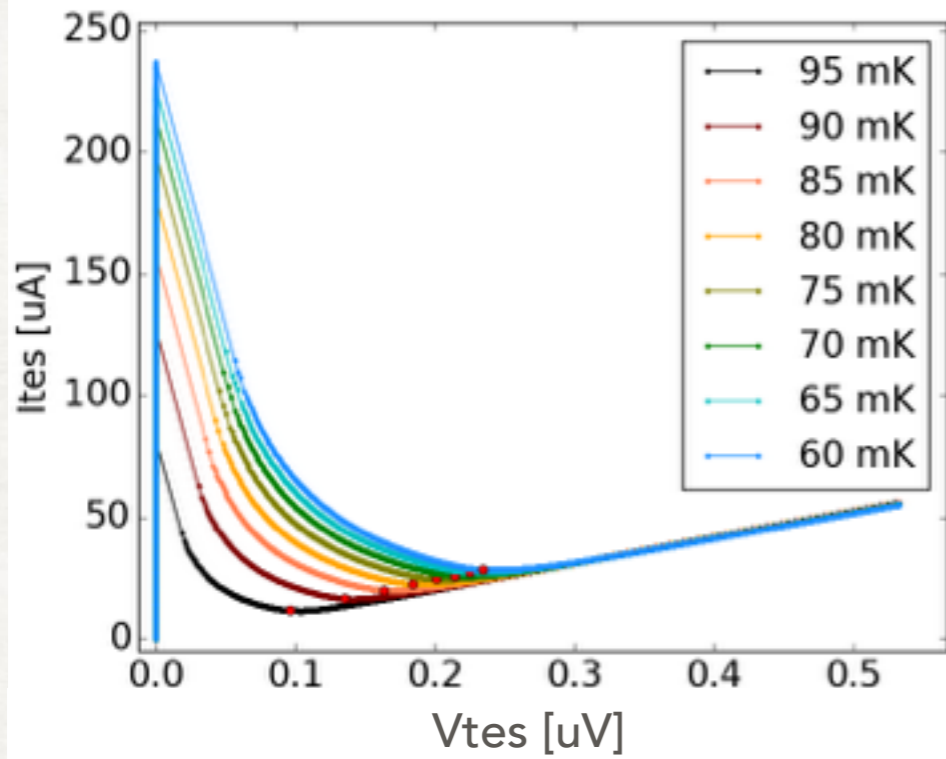
DEVICE PHOTO



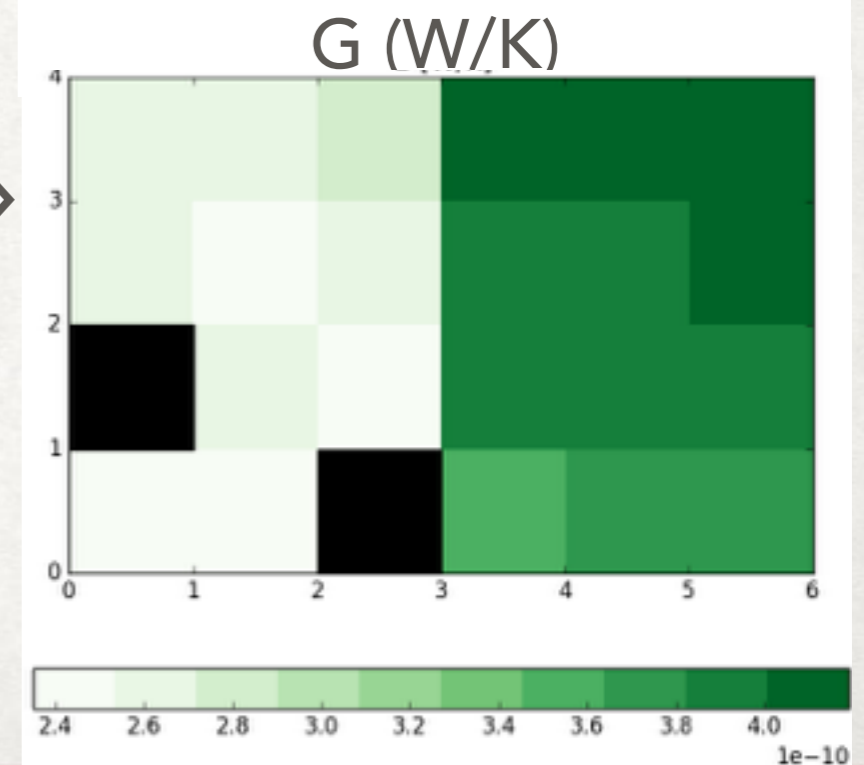
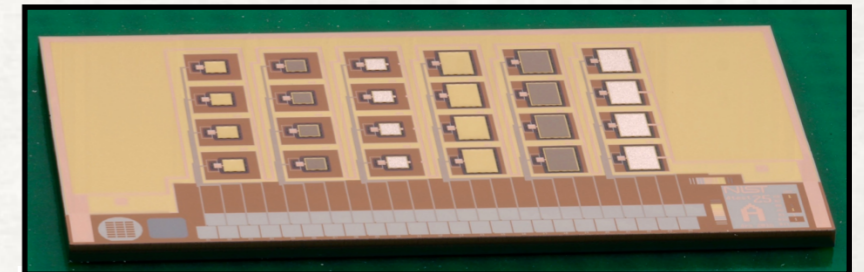
1µm Au



THERMAL CONDUCTANCE G



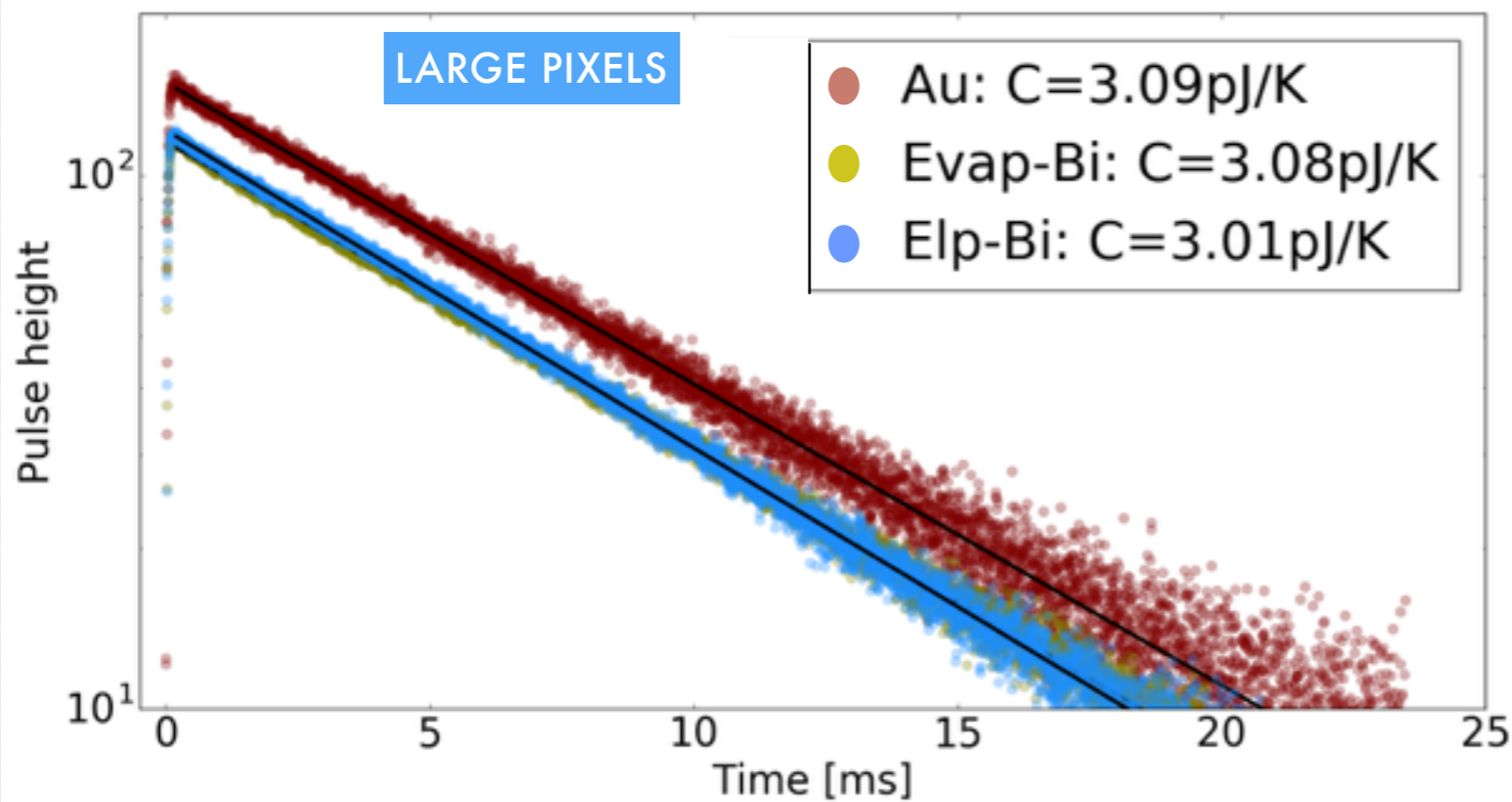
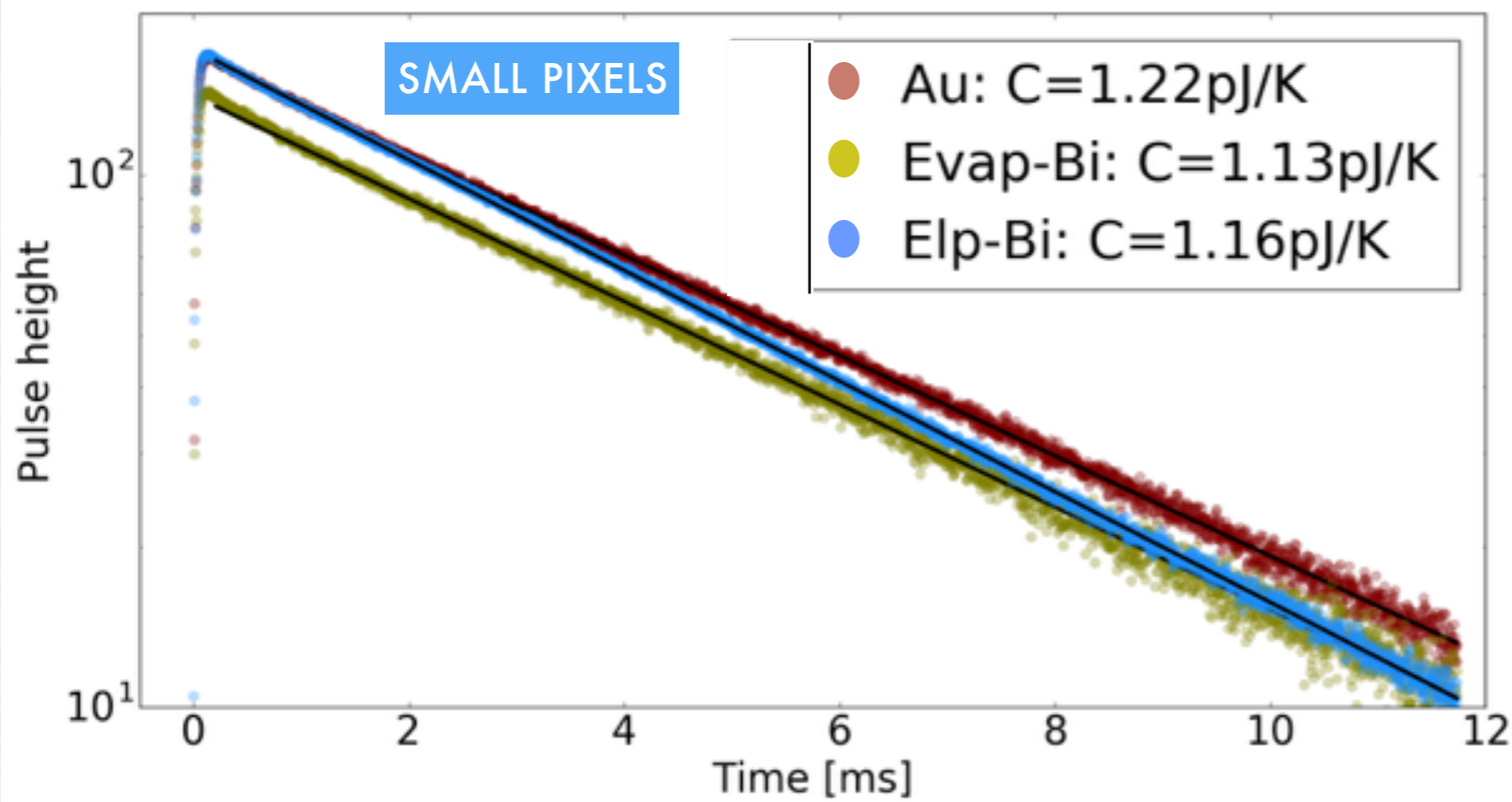
$$P_J = \frac{G_c}{nT_c^{n-1}} (T_c^n - T_b^n).$$



G values are calculated from IV measurements.

HEAT CAPACITY C

When the TES is biased high in transition, pulse decay time $\approx C/G$



	small pixels	large pixels	large/ small ratio
perimeter (μm)	1860	3000	1.61
average C (pJ/K)	1.16	3.03	2.61 $\approx 1.62^2$

a) 3 μm Bi does not sensibly increase C

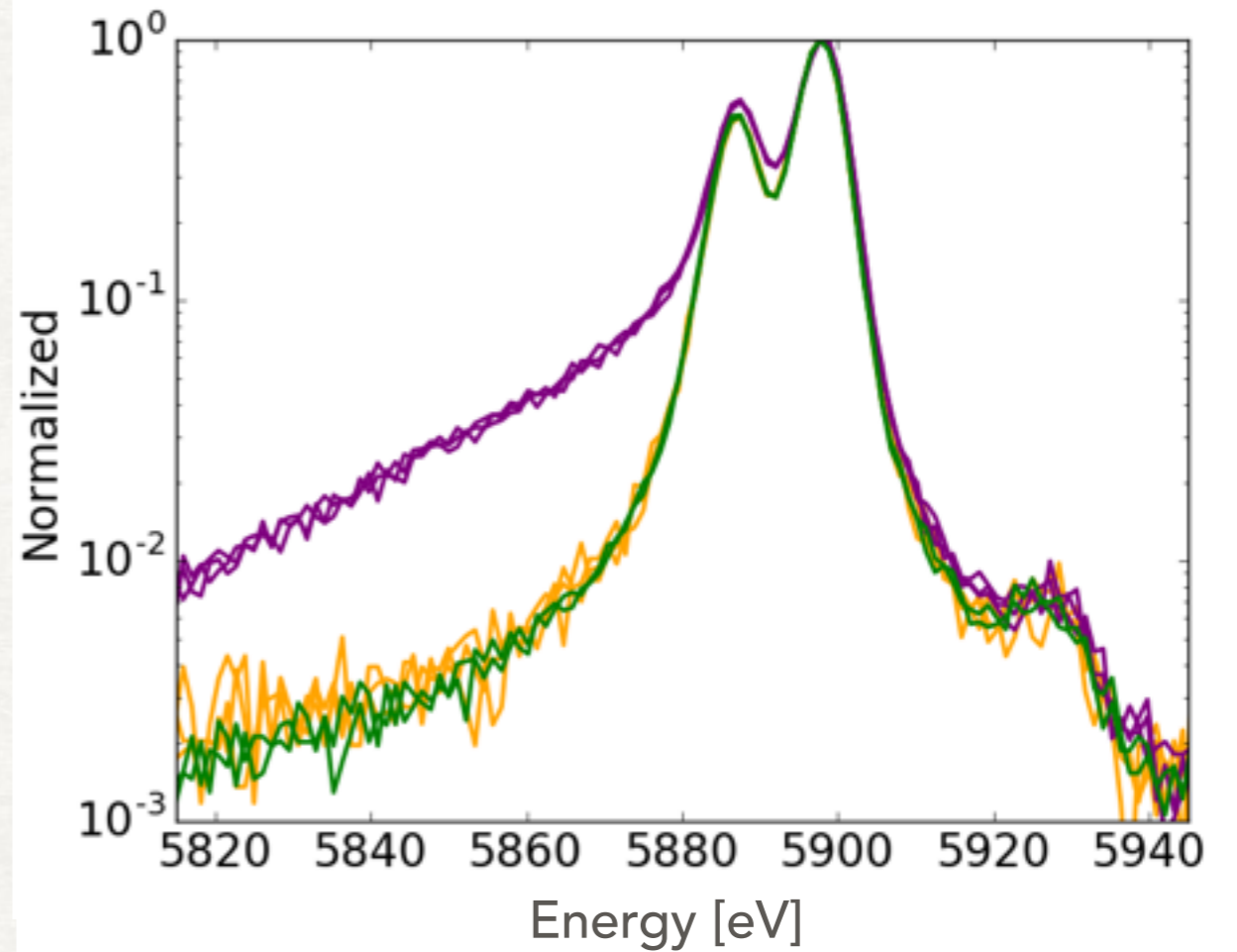
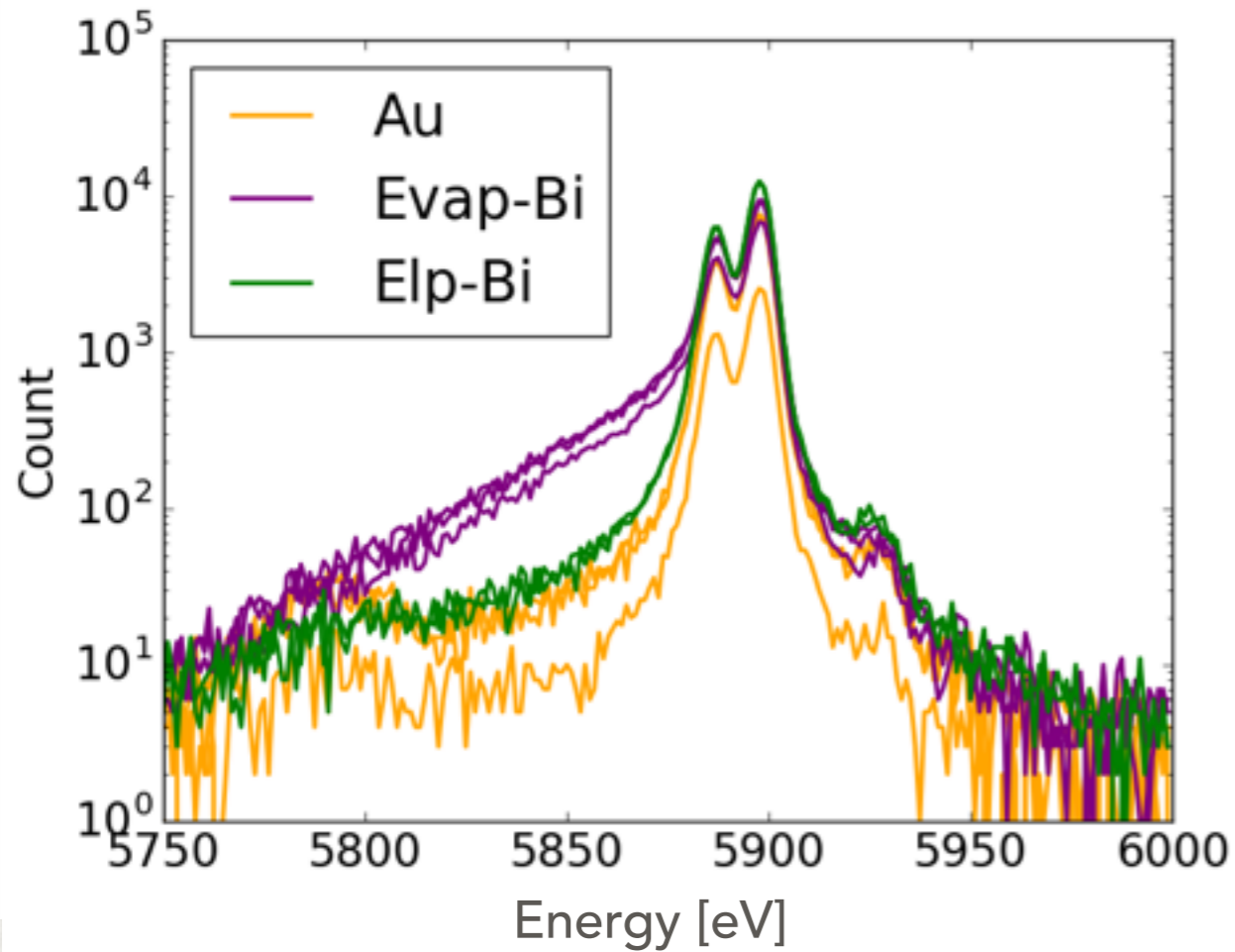
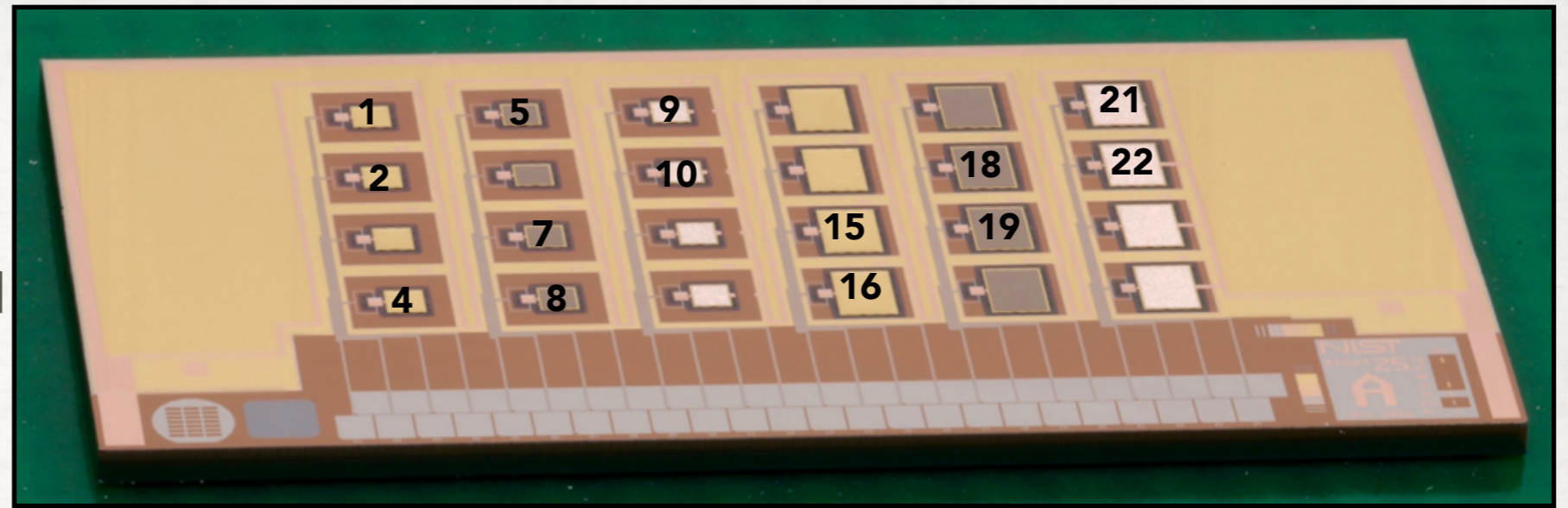
—> no resolution penalty.

b) C scales with the pixel volume

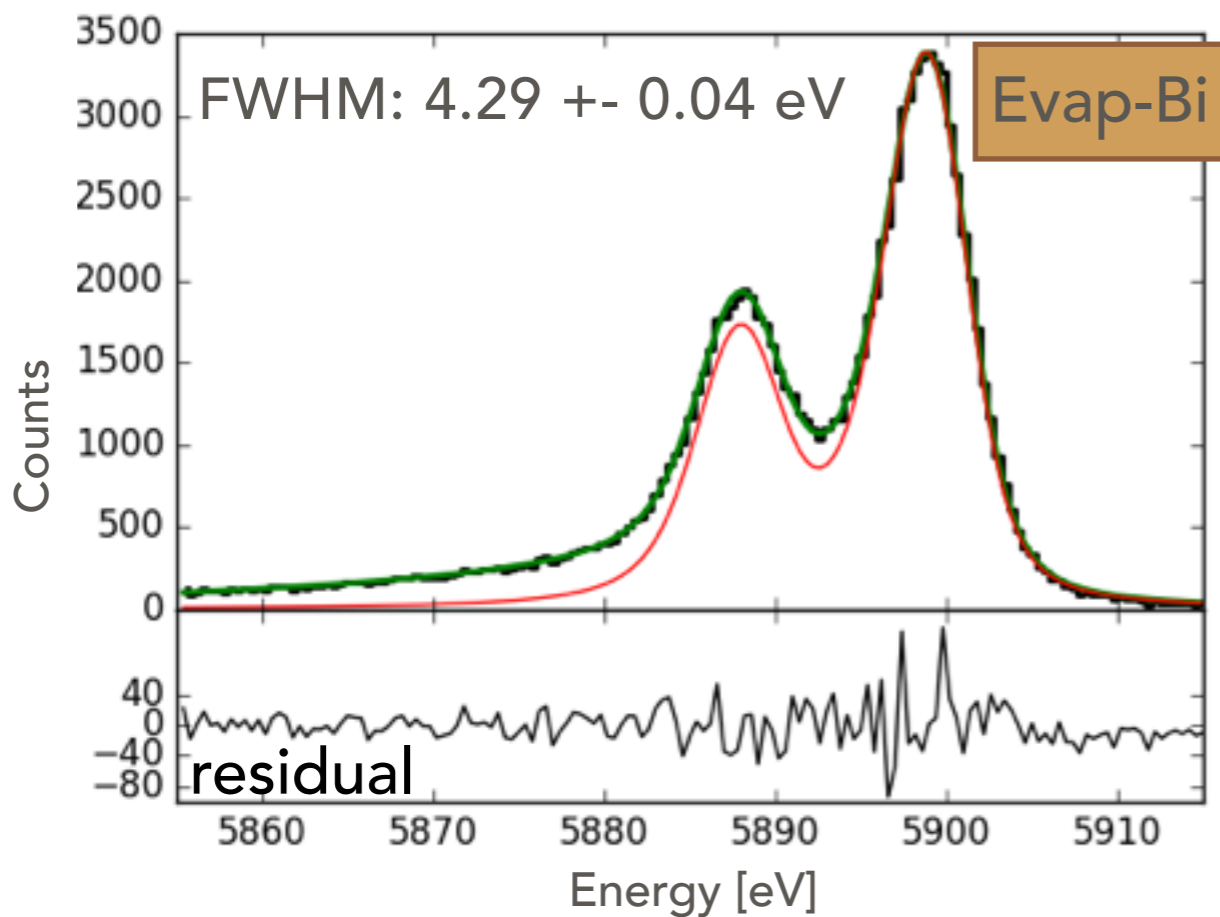
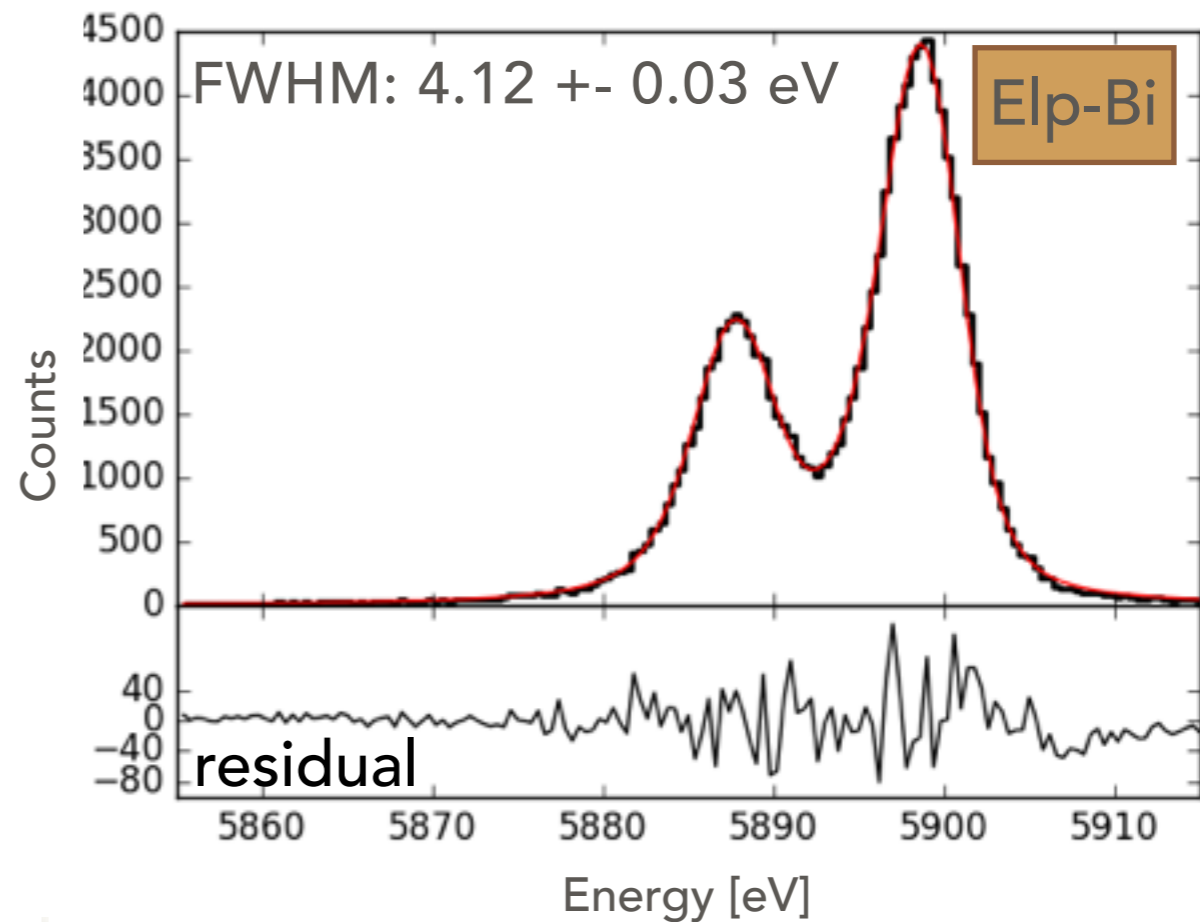
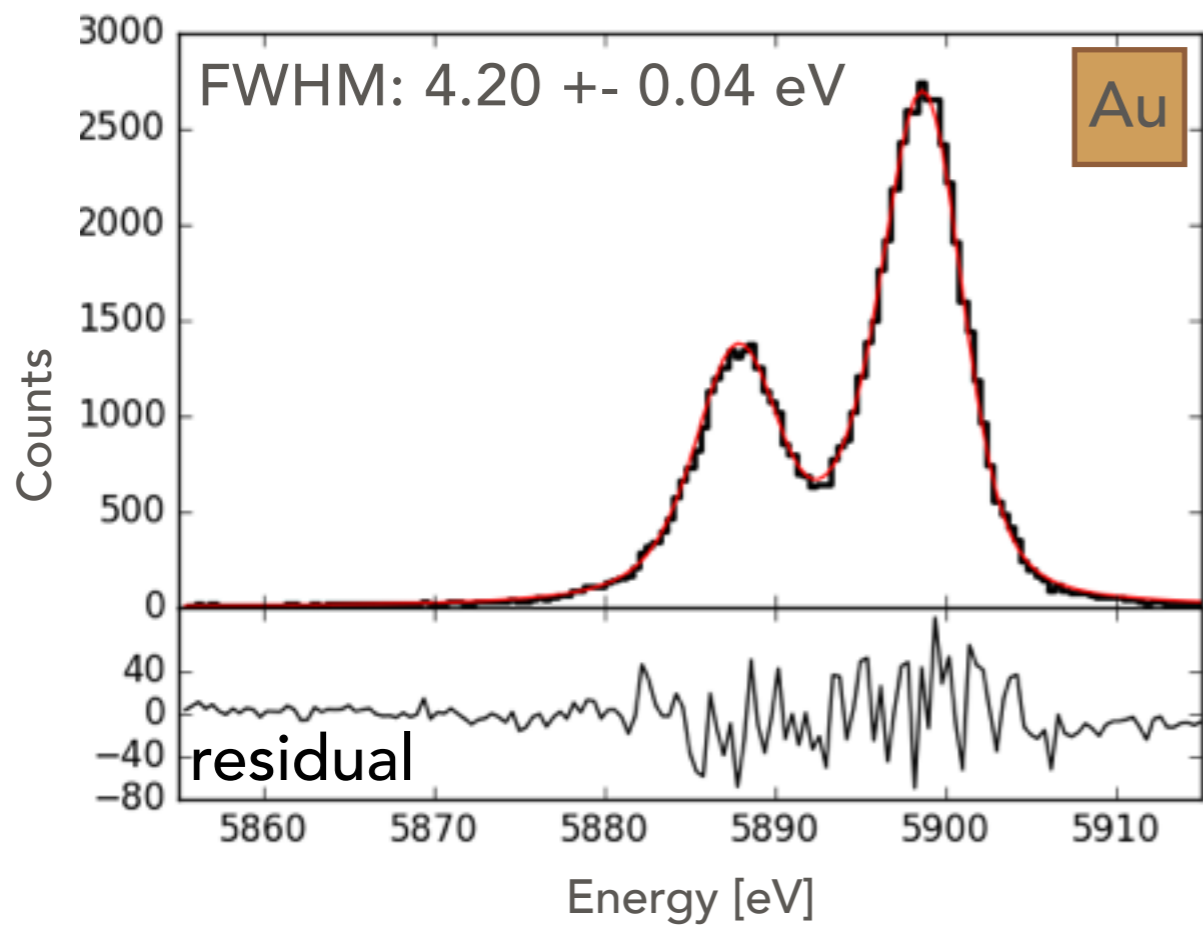
SPECTRA

Mn $K\alpha$ line
on selected small pixels
(designed for x-rays around
6 KeV)

SMALL PIXELS



- a) Low energy tails show in Evap-Bi pixels.
- b) Spectra from Au and Elp-Bi are same.



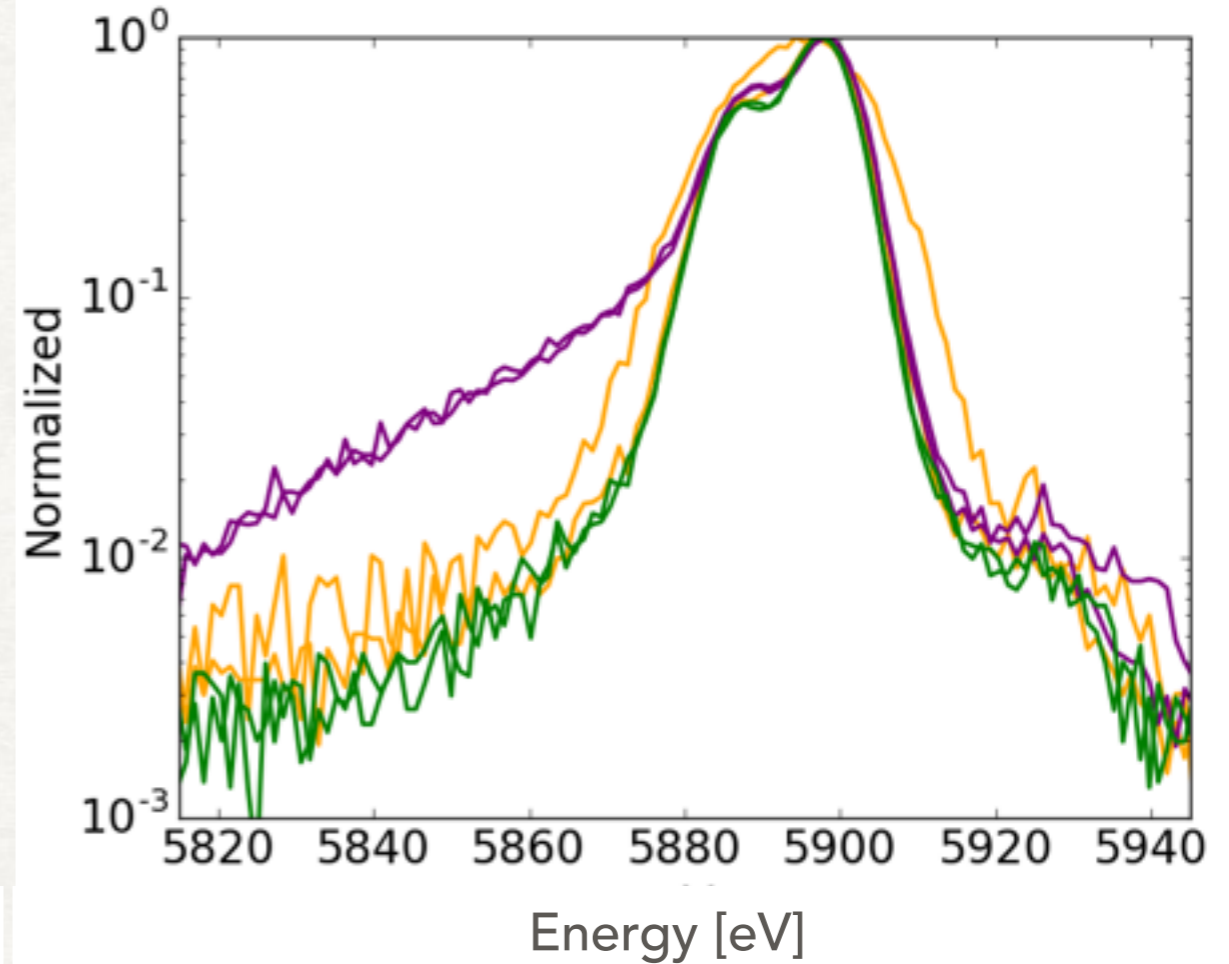
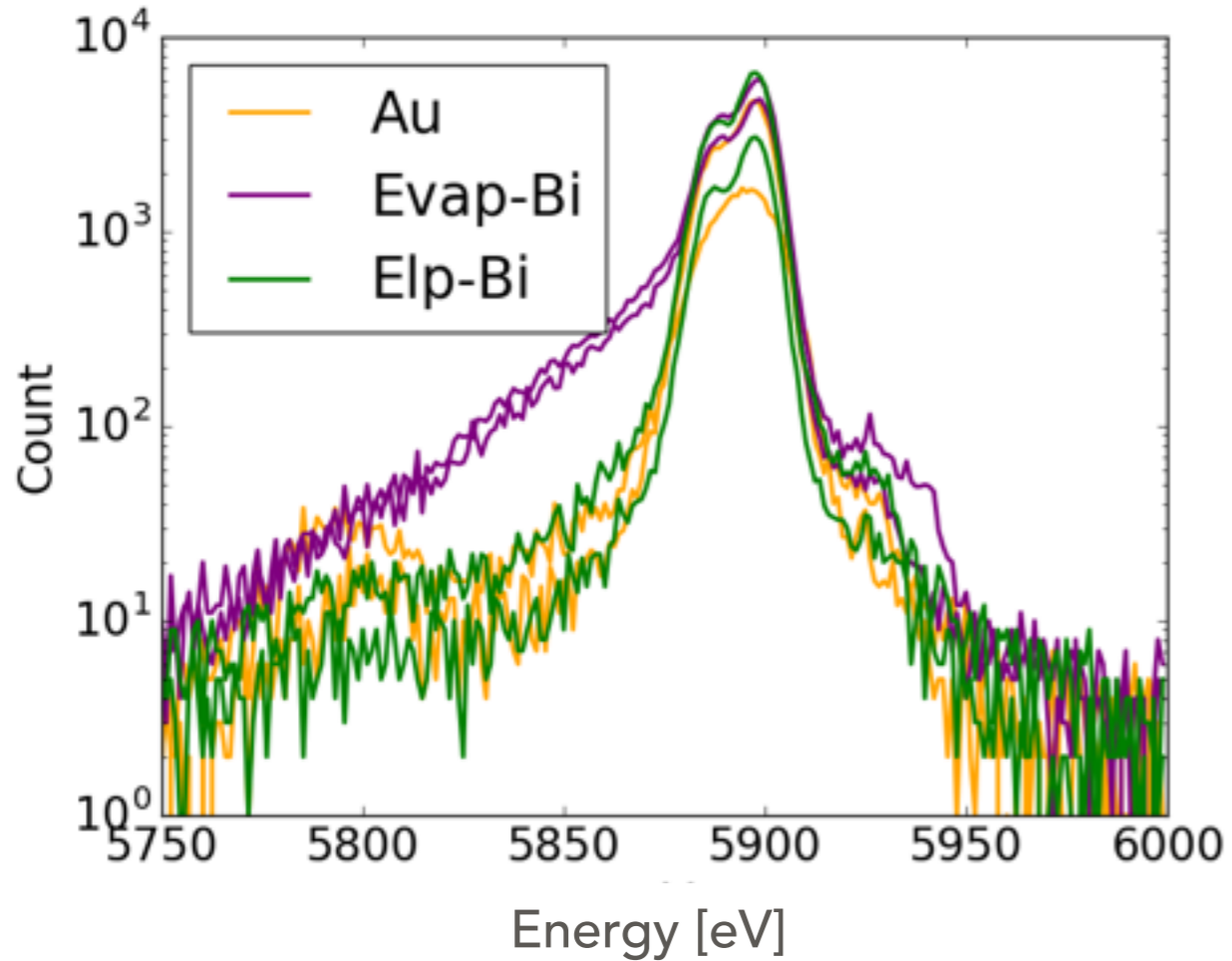
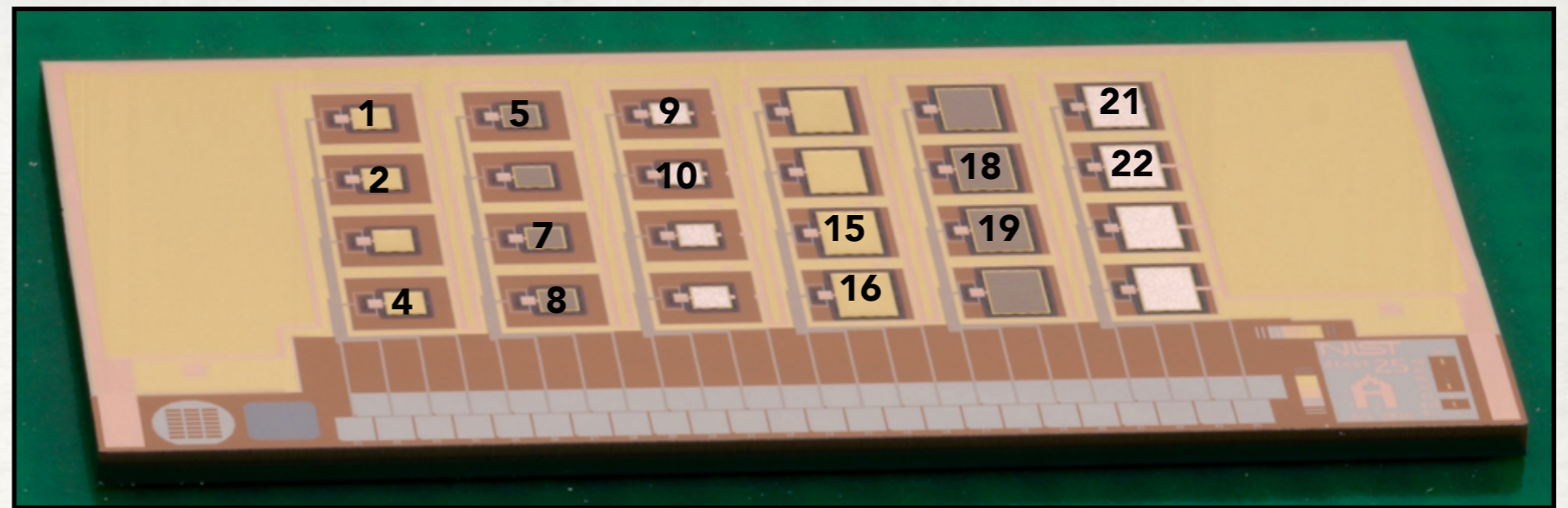
a) Energy resolutions for the three types of pixels are similar.

b) Evap-Bi has a low energy tail.

SPECTRA

Mn $K\alpha$ line
on selected large pixels
(designed for x-rays above
30 KeV)

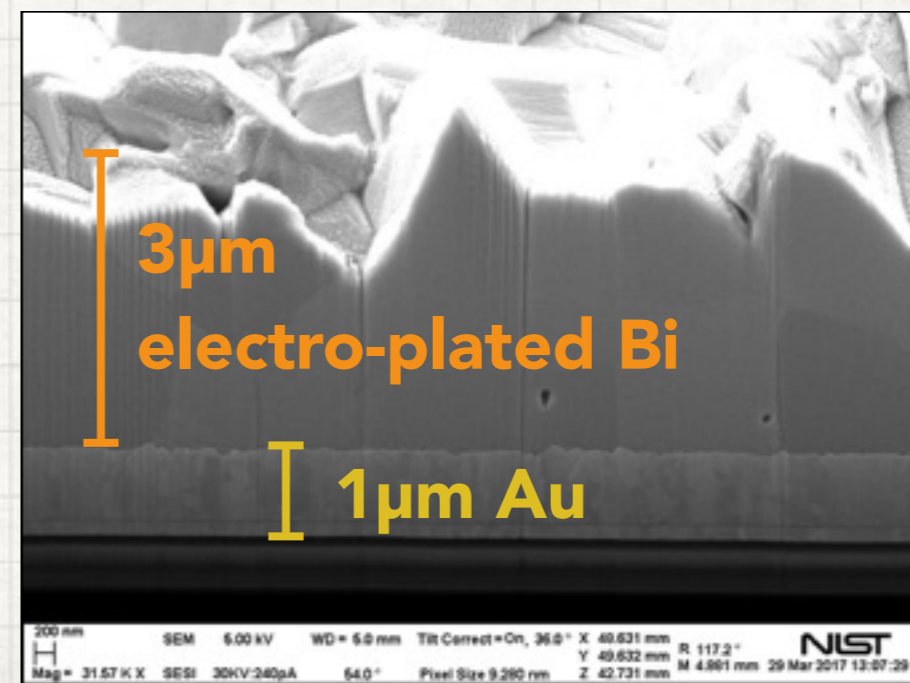
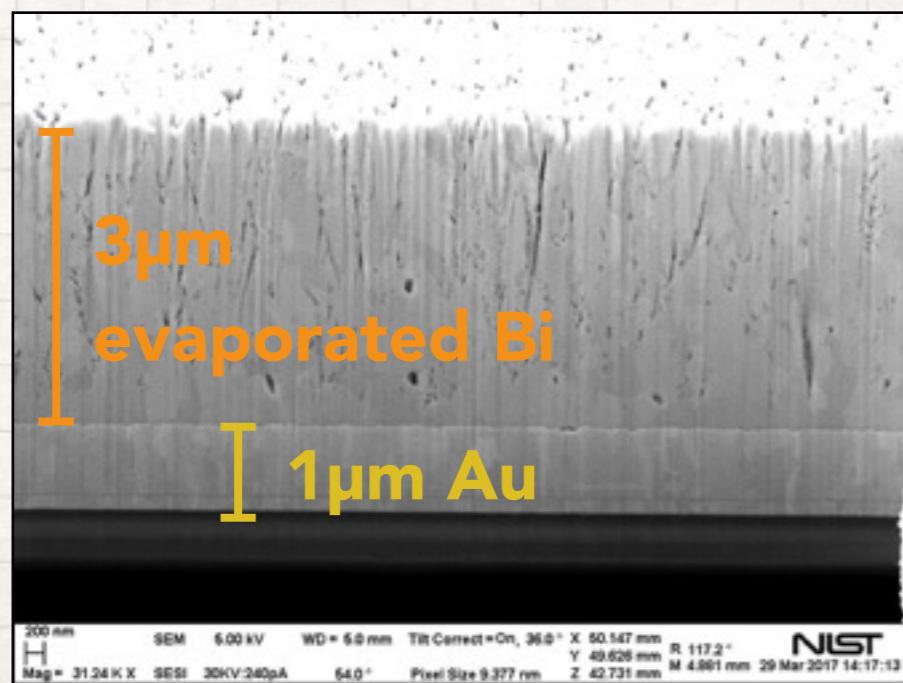
LARGE PIXELS



Show similar low energy tail feature.

CONCLUSION:

- a) Successfully fabricated devices with two different sizes absorbers made of **Au, Au + evaporated Bi and Au + electroplated Bi** on the same chip for easy comparison.
- b) TES pixels with Au, Au+Evap-Bi, Au+Elp-Bi absorbers show **similar C, and energy resolution.**
- c) The Au and Au+Elp-Bi pixels do not show **low energy tails** as the Au+Evap-Bi pixels.
- d) The physical mechanism is still unclear but is probably due to the different thermalization properties of the two very different films.



Thanks!

Q & A